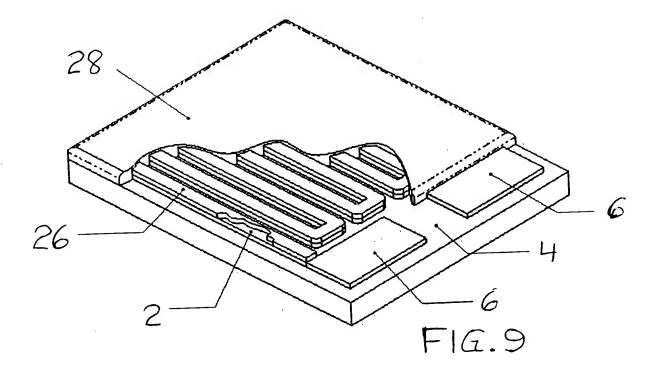
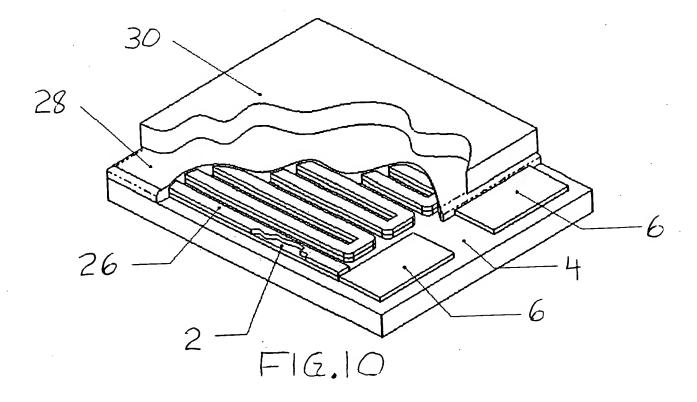
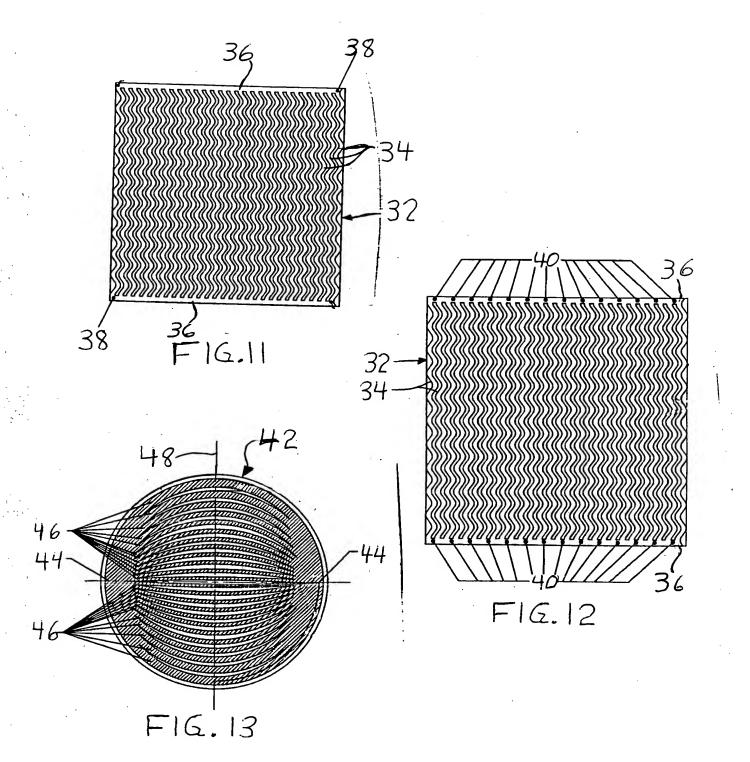
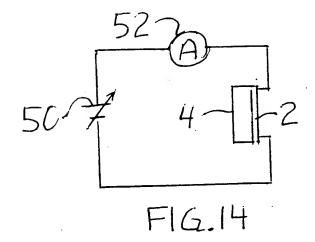


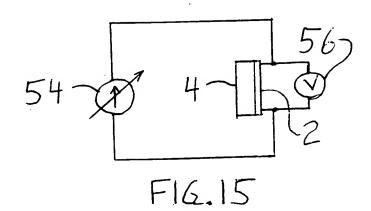
2 F16.8

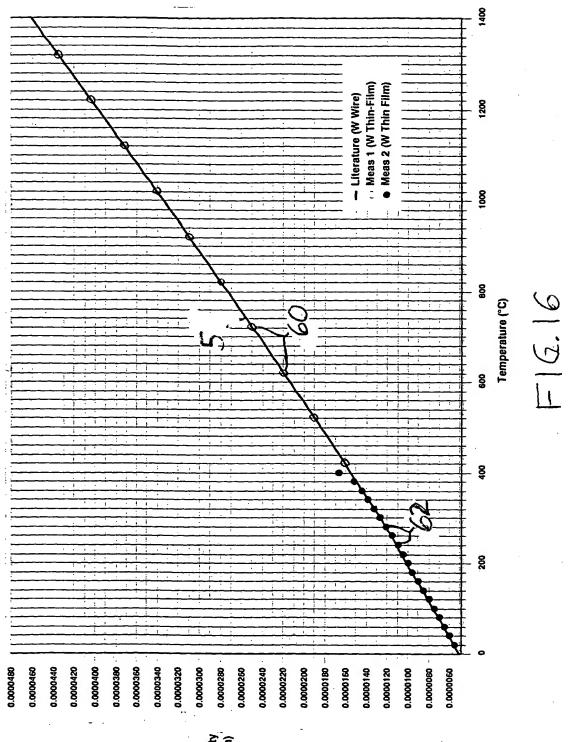




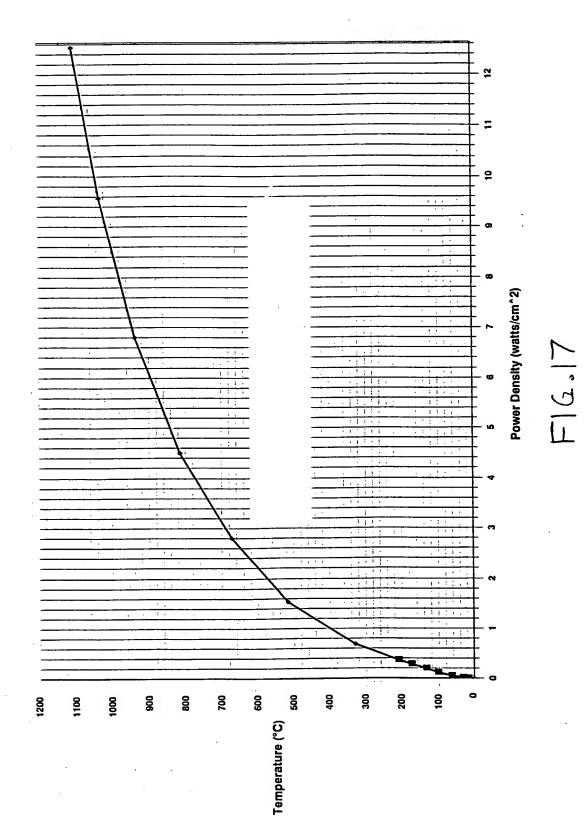


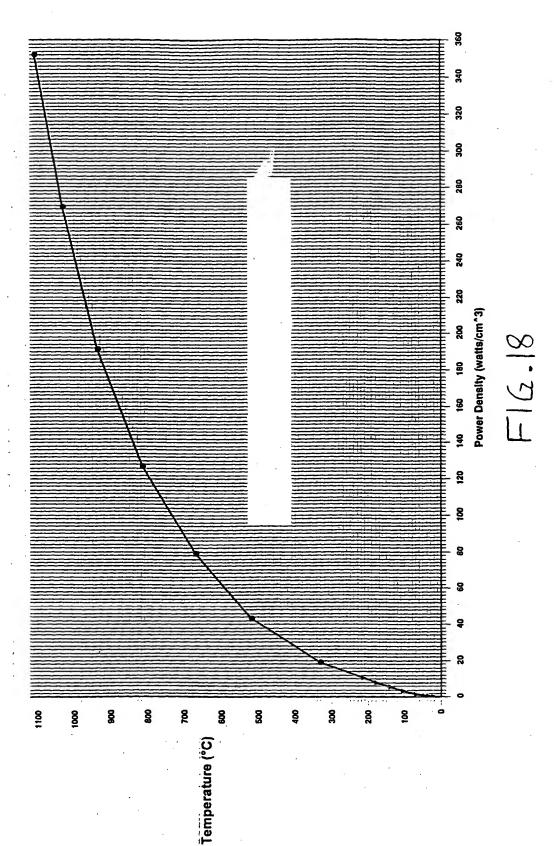


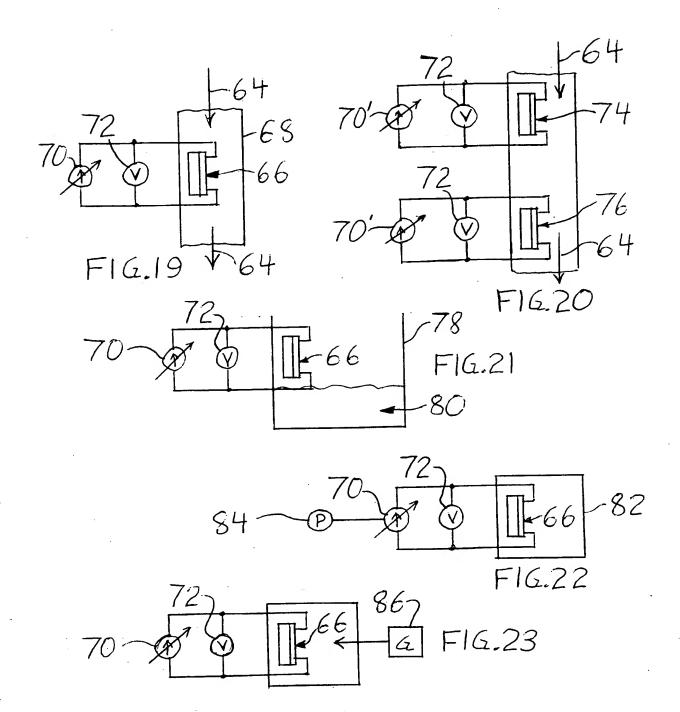




Resistivity (ohm-cm)







TEMPERATURE RANGE (°C) FOR DIFFERENT OPERATING ENVIRONMENTS

7	Air/Oxvaen	Ar, He or N_2	H ₂	Vacuum
# .514		00017 01 001	7-196 to ~1800	<-196 to ~1800
П	<-196 to ~260	-136 LU 1985		
	/-196 to ~1250	<-196 to ~1800	<-196 to ~1800	<-196 to ~1800
7			7	00012 04 961-7
C.	<-196 to ~1000	<-196 to ~1000	<-196 to ~1000	2001 00 001-3
n		7	Not Applicable	<-20 to ~1300
4	$< -20 \text{ to } \sim 1250$	<-20 to ~1300	STANSTIAGE JON	
	, 20 to ~1250	<-20 to ~1300	<-20 to ~1300	<-20 to ~1300
<u>.</u> -	0527 CO 07-3			
	7-196 +0 ~1250	<-196 to ~1300	Not Applicable	Not Applicable
0	02 04 /			196 + ~ 1300
α	<-196 to ~1250	<-196 to ~1300	<-196 to ~1300	2051 OJ 861->
O				196 +0 ~1300
o	<-196 to ~1250	<-196 to ~1300	<-196 to ~1300	2251 07 851-3
n				106 +0 ~1400
Ç	<-196 to ~1250	<-196 to ~1400	<-196 to ~1400	2-130 CD 7-3
0	١			

FIG. 24

TEMPERATURE SENSORS

Characteristic	1 01	tructure	Platinum Thin-Film	Thermistor
	FIG. #	Result	KTD	
Max. Zero-Drift Temperature (°C) · Steady State · Thermal Cycling	1,2,4,5,6,8,9,10	>1200 >1200	~500	0 >
Internal Drift Mechanisms				
(Within Zero-Drift Temp. Kange)	1,2,4,5,6,8,9,10	No	No	Yes
. Densification:	1,2,4,5,6,8,9,10	ON	ON	Xes
· Diffusion (Measureable):	1,2,4,5,6,8,9,10	No	ON.	מים א
 Expanison Mismatch (α) Substrate/Circuit Electrode/Circuit 		\$0.06 ~0	∸0.13 ~0	0 >0.3
Maximum Temperature (°C) vs				
Environments				
. Unencapsulated:	2,4,5,6,8,9,10	~1250	~850	~300
N. H. H. O.	1,2	~1800	~850	~300
o Hydrogen	1,2	~1800	Not Applicable	~300 ~300
• Vacuum	1,2	~1800	Not Applicable	0000
· Encapsulated	1,2,10	~1400	~850	~300
o Ar, He, N ₂	1,2,10	~1400 ~1400	. 850 ·	~300
· Vacuum	71.21.1		001	+0.01
Precision Limit: (°C)	1,2	±0.001	10000	*
Resp nse Time (Ratio to Platium Thin-Film RTD)	1,2,4,5,6,8,9,10	50.1	1	>2
Resp nse Type:	1,2,4,5,6,8,9,10	~Linear	~Linear	Exponential
Substrat Thermal Conductivity (W/cm/°K)	1-6,8-10	2.4	0.35	50.1
Marinim Tomporature Range (°C)	1,2	<-195 to ~1800	<-195 to ~850	<0 to ~800

HEATER STRUCTURES

						•	100
Characteristics	oleted Struct	ures	Bulk	Foil	Rods & Bars	Planar Heaters	Wire
	F1G. #	, and		oue [d	Line	Plane	Line
Source Type	1-6,8-10	Plane	Plane	2 tails			
2000							
Heating Modes		800	Yes	No	No	Yes	No
. Contact	1-6,8-10			202	۷۹۹	Yes	Yes
· Radiative	1-6,8-10	Yes	Yes	מ ט			1500
ΔT(°C)Heater-Object	1-6,8-10	~100	~100	~100	~800	001-	
@2"(5cm)							
Max.Temp.(°C) vs							
Environment			~1300	~1000	~1000	~700	~300
. Oxygen	3 (capped)	nnaT.~	200				~3000
X (1)	1.2	~1800	~1300	~3000	~3000	00/2	
. Аг, не, м ₂		000	~1300	~3000	~3000	~ 700	~3000
. Vacuum	1,2				0000	~700	~1800
· Hydrogen	1,2	~1800	~1300	~3000	0005~		
Time to Max. Temp.	1,2,4,5,6,8,9,10						
(°C), (Seconds)				/30	09>	09>	دع
. Heater	1,2,4,5,6,8,9,10	<3	099	25)			710
. Object@2" (Scm)	1,2,4,5,6,8,9,10	<4	<60	<120	<120	062	
		Excellent	Very Good	Very Good	Poor	Excellent	Poor
Radiative Heating	1,2,4,5,6,8,9,10	a contract of the contract of					
Sometime of the state of the st	01.0 0.1	2.4	2.4	~0.1	N/A	0.26-2.4	A/N
Substrate Thermal	01-010-1						
רסוומתררדווא וווי בייי							

FIG. 26